

## ATIR0811S

Photointerrupter - Reflective Type

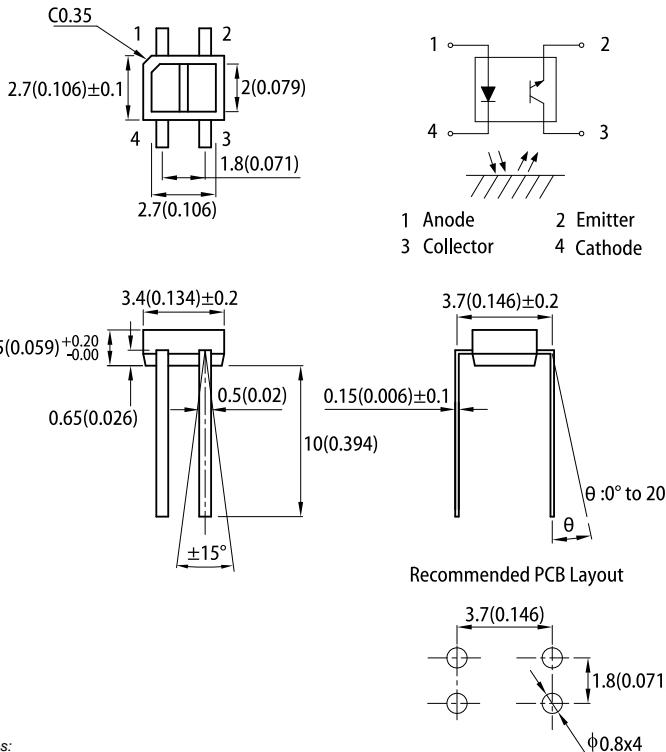
### FEATURES

- Compact and thin
- Visible light cut-off type
- High sensitivity
- RoHS compliant

### APPLICATIONS

- Cassette tape recorders, VCRs
- Floppy disk drives
- Various microcomputerized control equipment

### PACKAGE DIMENSIONS



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.25(0.01") unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

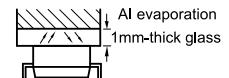
### ELECTRICAL / OPTICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$

Parameter		Symbol	Value				Units	Test Conditions
			Code.	Min.	Typ.	Max.		
Input	Forward voltage	$V_F$		1.0	1.2	1.5	V	$I_F=20\text{mA}$
	Reverse current	$I_R$		-	-	10	$\mu\text{A}$	$V_R=6\text{V}$
Output	Collector dark current	$I_{CEO}$		-	$10^{-9}$	$10^{-7}$	A	$V_{CE}=20\text{V}$
Transfer characteristics	Collector Current <sup>[1]</sup>		E	10	-	120	$\mu\text{A}$	$I_F=4\text{mA}, V_{CE}=2\text{V}$
			F	100	-	250		
			G	200	-	400		
	Leak Current <sup>[2]</sup>		$I_{LEAK}$		-	0.1	$\mu\text{A}$	$I_F=4\text{mA}, V_{CE}=2\text{V}$
	Response time	Rise time	$t_r$		-	20	$\mu\text{s}$	$V_{CE}=2\text{V}, I_C=100\mu\text{A}$ $R_L=1\text{K}\Omega, d=1\text{mm}$
		Fall time	$t_f$		-	20	$\mu\text{s}$	

Notes:

1. Test condition of collector current is shown below.
2. Without reflective object.
3. Excess driving current and/or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

Test Condition and Arrangement for Collector Current



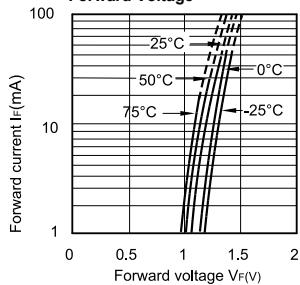
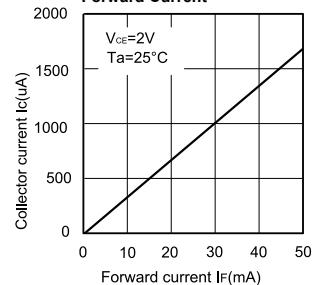
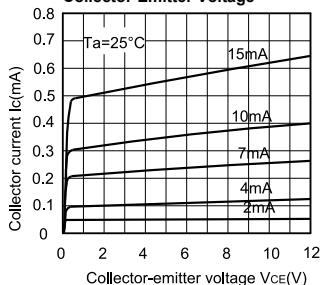
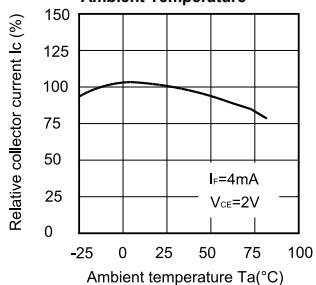
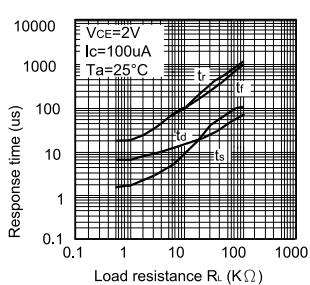
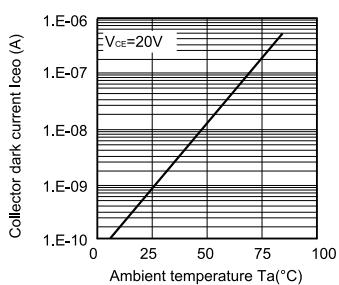
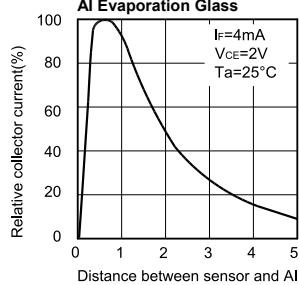
ABSOLUTE MAXIMUM RATINGS at  $T_A=25^\circ\text{C}$ 

Parameter		Symbol	Rating	Unit
Input	Forward current	$I_F$	50	mA
	Reverse voltage	$V_R$	6	V
	Power dissipation	$P_D$	75	mW
	Peak Forward Current (Pulse Width $\leq 100\mu\text{s}$ , Duty Cycle=1%)	$I_{FP}$	1	A
Output	Collector-emitter voltage	$V_{CEO}$	35	V
	Emitter-collector voltage	$V_{ECO}$	6	V
	Collector current	$I_C$	20	mA
	Collector power dissipation	$P_C$	75	mW
Operating temperature		$T_{opr}$	-25~+85	$^\circ\text{C}$
Storage temperature		$T_{stg}$	-40~+100	$^\circ\text{C}$
Soldering temperature (1/16 inch from body for 5 seconds)		$T_{sol}$	260	$^\circ\text{C}$

Note:

1. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

## TECHNICAL DATA

Fig. 1 Forward Current vs.  
Forward VoltageFig. 2 Collector Current vs.  
Forward CurrentFig. 3 Collector Current vs.  
Collector-Emitter VoltageFig. 4 Relative Collector Current vs.  
Ambient TemperatureFig. 5 Response Time vs.  
Load ResistanceFig. 6 Collector Dark Current vs.  
Ambient TemperatureFig. 7 Relative Collector Current vs.  
Distance Between Sensor and  
Al Evaporation GlassFig. 8 Relative Collector Current vs.  
Card Moving Distance (1)